Hideo Kosaka

List of Publications by Year in descending order

Source: https://exaly.com/author-pdf/4205062/publications.pdf

Version: 2024-02-01

186265 4,327 78 28 citations h-index papers

g-index 80 80 80 2544 docs citations times ranked citing authors all docs

110387

64

#	Article	IF	CITATIONS
1	Quantum error correction of spin quantum memories in diamond under a zero magnetic field. Communications Physics, 2022, 5, .	5.3	6
2	Complete Bell state measurement of diamond nuclear spins under a complete spatial symmetry at zero magnetic field. Applied Physics Letters, 2022, 120, .	3.3	4
3	Geometric entanglement of a photon and spin qubits in diamond. Communications Physics, 2021, 4, .	5.3	9
4	Quantum teleportation-based state transfer of photon polarization into a carbon spin in diamond. Communications Physics, 2019, 2, .	5.3	26
5	Dynamical Decoupling of a Geometric Qubit. Physical Review Applied, 2019, 12, .	3.8	12
6	Two-step frequency conversion for connecting distant quantum memories by transmission through an optical fiber. Japanese Journal of Applied Physics, 2018, 57, 062801.	1.5	11
7	Universal holonomic single quantum gates over a geometric spin with phase-modulated polarized light. Optics Letters, 2018, 43, 2380.	3.3	41
8	Universal holonomic quantum gates over geometric spin qubits with polarised microwaves. Nature Communications, 2018, 9, 3227.	12.8	59
9	Compact frequency-stabilized pump laser for wavelength conversion in long-distance quantum communication. Journal of the Optical Society of America B: Optical Physics, 2018, 35, 2023.	2.1	1
10	Optical holonomic single quantum gates with a geometric spin under a zero field. Nature Photonics, 2017, 11, 309-314.	31.4	117
11	Geometric spin echo under zero field. Nature Communications, 2016, 7, 11668.	12.8	23
12	High-fidelity transfer and storage of photon states in a single nuclear spin. Nature Photonics, 2016, 10, 507-511.	31.4	108
13	Absorption-based quantum communication with NV centres. New Journal of Physics, 2015, 17, 103012.	2.9	7
14	Entangled Absorption of a Single Photon with a Single Spin in Diamond. Physical Review Letters, 2015, 114, 053603.	7.8	37
15	Process tomography of coherent state transfer from light polarization to electron spin polarization in a semiconductor. Physical Review B, 2014, 89, .	3.2	3
16	Excitonic Rabi oscillations in self-assembled quantum dots in the presence of a local field effect. Physical Review B, 2013, 87, .	3.2	10
17	Creation of entangled spin qubits between distant quantum dots. Physical Review B, 2013, 88, .	3.2	8
18	Coherent transfer of time-bin photons to electron spins in a semiconductor. Physical Review A, 2012, 85, .	2.5	4

#	Article	IF	Citations
19	Excitonic Rabi oscillations in selfâ€assembled quantum dots studied by photon echoes. Physica Status Solidi C: Current Topics in Solid State Physics, 2012, 9, 2513-2516.	0.8	O
20	Coherent Transfer of Time-bin Photons to Electron Spins in a Semiconductor. , 2012, , .		0
21	Photon-to-electron quantum information transfer. Journal of Applied Physics, 2011, 109, 102414.	2.5	10
22	Electron spin state tomography with coherent Kerr effect. Applied Physics Letters, 2011, 99, .	3.3	5
23	Scheme for Bell state measurement in a g-factor engineered double dot. Journal of Physics: Conference Series, 2010, 200, 112012.	0.4	0
24	Single charge detection of an electron created by a photon in a g-factor engineered quantum dot. Applied Physics Letters, 2010, 96, .	3.3	27
25	Single-electron spin resonance in a g-factor-controlled semiconductor quantum dot. Physica E: Low-Dimensional Systems and Nanostructures, 2010, 42, 821-824.	2.7	3
26	Proposal of a full Bell state analyzer for spin qubits in a double quantum dot. Physical Review B, 2010, 81, .	3.2	7
27	Measurement of Electron Spin States in a Semiconductor Quantum Well Using Tomographic Kerr Rotation. Japanese Journal of Applied Physics, 2010, 49, 04DJ09.	1.5	2
28	Electrical Measurement of a Two-Electron Spin State in a Double Quantum Dot. Physical Review Letters, 2009, 103, 046806.	7.8	6
29	Spin state tomography of optically injected electrons in a semiconductor. Nature, 2009, 457, 702-705.	27.8	87
30	Observation of optical-fibre Kerr nonlinearity at the single-photon level. Nature Photonics, 2009, 3, 95-98.	31.4	125
31	All-optical phase modulations in a silicon wire waveguide at ultralow light levels. Applied Physics Letters, 2009, 95, .	3.3	17
32	Magneto-optical Kerr effect tomography of an electron spin state in a semiconductor quantum dot. , 2009, , .		0
33	Coherent Transfer of Light Polarization to Electron Spins in a Semiconductor. Physical Review Letters, 2008, 100, 096602.	7.8	105
34	Generation of polarization entanglement from spatially correlated photons in spontaneous parametric down-conversion. Physical Review A, 2008, 77, .	2.5	6
35	Lossless all-optical phase gate using a polarization-division Sagnac interferometer applicable to a waveguide-type Kerr medium. Applied Physics Letters, 2007, 91, 171119.	3.3	10
36	Polarization transfer from photon to electron spin in g factor engineered quantum wells. Applied Physics Letters, 2007, 90, 113511.	3.3	9

#	Article	IF	CITATIONS
37	Theoretical Analysis of the Optimal Conditions for Photon-Spin Quantum State Transfer. Journal of the Physical Society of Japan, 2007, 76, 114004.	1.6	3
38	Littrow-type external-cavity diode laser with a triangular prism for suppression of the lateral shift of output beam. Review of Scientific Instruments, 2006, 77, 046102.	1.3	11
39	Single-photon Interference over 150 km Transmission Using Silica-based Integrated-optic Interferometers for Quantum Cryptography. Japanese Journal of Applied Physics, 2004, 43, L1217-L1219.	1.5	76
40	Comparative analysis of the hspA mutant and wild-type Synechocystis sp. strain PCC 6803 under salt stress: evaluation of the role of hspA in salt-stress management. Archives of Microbiology, 2004, 182, 487-497.	2.2	30
41	Single photoelectron trapping, storage, and detection in a field effect transistor. Physical Review B, 2003, 67, .	3.2	47
42	Single-photon interference experiment over 100â€km for quantum cryptography system using balanced gated-mode photon detector. Electronics Letters, 2003, 39, 1199.	1.0	86
43	Photoconductance quantization in a single-photon detector. Physical Review B, 2002, 65, .	3.2	28
44	Electron g factor engineering in III-V semiconductors for quantum communications. Electronics Letters, 2001, 37, 464.	1.0	100
45	Lightwave propagation through a 120° sharply bent single-line-defect photonic crystal waveguide. Applied Physics Letters, 2000, 76, 952-954.	3.3	270
46	Splitting of triply degenerate refractive indices by photonic crystals. Physical Review B, 2000, 62, 1477-1480.	3.2	21
47	Photonic-crystal spot-size converter. Applied Physics Letters, 2000, 76, 268-270.	3.3	55
48	Photonic crystals for micro lightwave circuits using wavelength-dependent angular beam steering. Applied Physics Letters, 1999, 74, 1370-1372.	3.3	259
49	Self-collimating phenomena in photonic crystals. Applied Physics Letters, 1999, 74, 1212-1214.	3.3	697
50	Smart integration and packaging of 2D VCSEL's for high-speed parallel links. IEEE Journal of Selected Topics in Quantum Electronics, 1999, 5, 184-192.	2.9	22
51	Superprism phenomena in photonic crystals: toward microscale lightwave circuits. Journal of Lightwave Technology, 1999, 17, 2032-2038.	4.6	195
52	Polarization-controlled single-mode VCSEL. IEEE Journal of Quantum Electronics, 1998, 34, 1009-1015.	1.9	39
53	Superprism phenomena in photonic crystals. Physical Review B, 1998, 58, R10096-R10099.	3.2	811
54	High-speed VCSEL of modulation bandwidth over 7.0 GHz and its application to 100 m PCF datalink. Journal of Lightwave Technology, 1998, 16, 870-875.	4.6	25

#	Article	IF	Citations
55	Self-stopping selective-oxidation process of AlAs. Applied Physics Letters, 1998, 72, 2310-2312.	3.3	12
56	1-Gb/s modulation characteristics of a vertical-cavity surface-emitting laser array module. IEEE Photonics Technology Letters, 1997, 9, 146-148.	2.5	10
57	A 16×16 optical full-cross-bar connection module with VCSEL-array push/pull module and polymer-waveguide coupler connector. IEEE Photonics Technology Letters, 1997, 9, 244-246.	2.5	10
58	A two-dimensional optical parallel transmission using a vertical-cavity surface-emitting laser array module and an image fiber. IEEE Photonics Technology Letters, 1997, 9, 253-255.	2.5	48
59	An excellent weight-updating-linearity EEPROM synapse memory cell for self-learning Neuron-MOS neural networks. IEEE Transactions on Electron Devices, 1995, 42, 135-143.	3.0	29
60	Alternately perpendicular polarisation in chequer-pattern matrix arrays of VCSELs. Electronics Letters, 1995, 31, 1573-1574.	1.0	16
61	A neuron-MOS neural network using self-learning-compatible synapse circuits. IEEE Journal of Solid-State Circuits, 1995, 30, 913-922.	5.4	35
62	Gigabit-rate optical-signal transmission using vertical-cavity surface-emitting lasers with large-core plastic-cladding fibers. IEEE Photonics Technology Letters, 1995, 7, 926-928.	2.5	34
63	Complete polarization control of 8×8 verticalâ€cavity surfaceâ€emitting laser matrix arrays. Applied Physics Letters, 1995, 66, 908-910.	3.3	106
64	Control of light-output polarization for surface-emitting-laser type device by strained active layer grown on misoriented substrate. IEEE Journal of Quantum Electronics, 1995, 31, 636-642.	1.9	28
65	Thermal Analysis of Laser-Emission Surface-Normal Optical Devices with a Vertical Cavity. Japanese Journal of Applied Physics, 1994, 33, 859-863.	1.5	12
66	Uniform characteristics with low threshold and high efficiency for a single-transverse-mode vertical-cavity surface-emitting laser-type device array. IEEE Photonics Technology Letters, 1994, 6, 323-325.	2.5	17
67	Indistinct threshold laser operation in a pnpn vertical to surface transmission electrophotonic device with a vertical cavity. IEEE Journal of Quantum Electronics, 1993, 29, 403-410.	1.9	13
68	Effect of sidewall reflector on current versus light output in a pnpn vertical-to-surface transmission electrophotonic device with a vertical cavity. IEEE Journal of Quantum Electronics, 1993, 29, 2006-2012.	1.9	14
69	High electronic-optical conversion efficiency in a vertical-to-surface transmission electro-photonic device with a vertical cavity. IEEE Photonics Technology Letters, 1993, 5, 136-139.	2.5	13
70	Pixels Consisting of Double Vertical-Cavity Detector and Single Vertical-Cavity Laser Sections for 2-D Bidirectional Optical Interconnections. Japanese Journal of Applied Physics, 1993, 32, 600-603.	1.5	9
71	Double-Mesa-Structure Vertical-to-Surface Transmission Electro-Photonic Device with a Vertical Cavity. Japanese Journal of Applied Physics, 1993, 32, 604-608.	1.5	12
72	Cascadable optical switching characteristics in verticalâ€toâ€surface transmission electrophotonic devices operated as vertical cavity lasers. Applied Physics Letters, 1992, 60, 799-801.	3.3	21

#	Article	IF	CITATION
73	Vertical-to-surface transmission electrophotonic device with a pnpn structure and vertical cavity. Optical and Quantum Electronics, 1992, 24, S121-S132.	3.3	12
74	Verticalâ€toâ€surface transmission electrophotonic device and its application to optical interconnection. Electronics and Communications in Japan, 1992, 75, 20-31.	0.2	0
75	Surfaceâ€emitting laser operation in verticalâ€toâ€surface transmission electrophotonic devices with a vertical cavity. Applied Physics Letters, 1991, 58, 1250-1252.	3.3	93
76	Current versus Light-Output Characteristics with No Definite Threshold in pnpn Vertical to Surface Transmission Electro-Photonic Devices with a Vertical Cavity. Japanese Journal of Applied Physics, 1991, 30, L602-L604.	1.5	42
77	Detector Characteristics of a Vertical-Cavity Surface-Emitting Laser. Japanese Journal of Applied Physics, 1991, 30, L1172-L1174.	1.5	25
78	Decay time measurements of intrinsic luminescence in alkali halides using single-bunched light pulses from UVSOR. Physica Scripta, 1990, 41, 120-123.	2.5	35